SQD70140EL



Vishay Siliconix

RoHS

COMPLIANT

HALOGEN

FREE

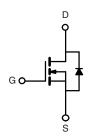
Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	100			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0150			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0190			
I _D (A)	30			
Configuration	Single			
Package	TO-252			



FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- 100 % $\rm R_g$ and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_C = 25 \text{ °C}$, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V _{DS}	100	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current	$T_C = 25 \ ^{\circ}C \ ^{a}$	Ŀ	30		
Continuous Drain Current	T _C = 125 °C	I _D	27		
Continuous Source Current (Diode Conduction) ^a	I _S	30	А		
Pulsed Drain Current ^b		I _{DM}	120		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	34		
Single Pulse Avalanche Energy		E _{AS}	58	mJ	
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	71	w	
	T _C = 125 °C	۲D	23	٧V	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W
Junction-to-Case (Drain)		R _{thJC}	2.1	0/10

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT		
Static					1			
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA		100	-	-		
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \mu A$		-	2.5	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	250		
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	30	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0120	0.0150	Ω	
		V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0255		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0320		
		$V_{GS} = 4.5 V$	I _D = 20 A	-	0.0145	0.0190		
Forward Transconductance b	9 _{fs}	V _{DS}	V _{DS} = 15 V, I _D = 25 A		58	-	S	
Dynamic ^b	•				•		•	
Input Capacitance	C _{iss}		_S = 0 V V _{DS} = 25 V, f = 1 MHz	-	1565	2100	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	800	1100		
Reverse Transfer Capacitance	C _{rss}			-	65	100		
Total Gate Charge ^c	Qg		= 10 V V _{DS} = 50 V, I _D = 30 A		26.5	40		
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = 10 V$			5.5	-	nC	
Gate-Drain Charge ^c	Q _{gd}			-	5.5	-	1	
Gate Resistance	Rg	f = 1 MHz		1.1	2.3	3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 50 \text{ V}, \text{ R}_{\text{L}} = 1.67 \ \Omega$ $\text{I}_{\text{D}} \cong 30 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \ \Omega$		-	7	15		
Rise Time ^c	tr			-	19	30	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	18	30		
Fall Time ^c	t _f			-	59	95		
Source-Drain Diode Ratings and Chara	acteristics ^b	•						
Pulsed Current ^a	I _{SM}			-	-	120	Α	
Forward Voltage	V _{SD}	I _F = 30 A, V _{GS} = 0 V		-	0.94	1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

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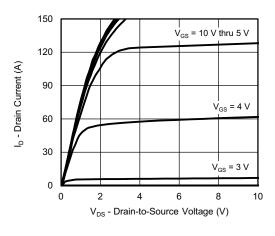
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

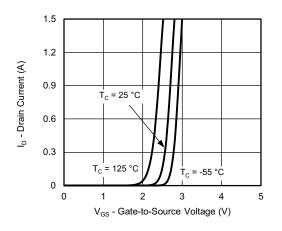
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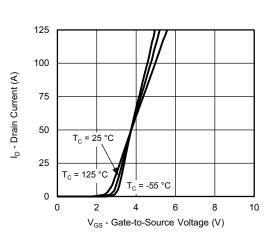
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



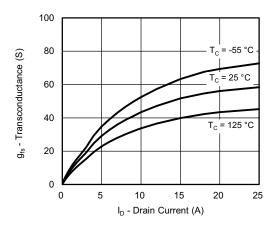
Output Characteristics



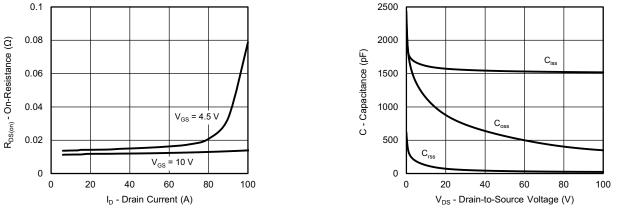
Transfer Characteristics



Transfer Characteristics



Transconductance



On-Resistance vs. Drain Current

Capacitance

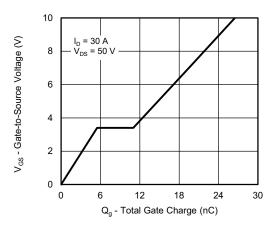
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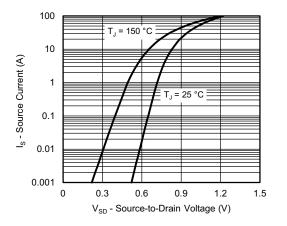
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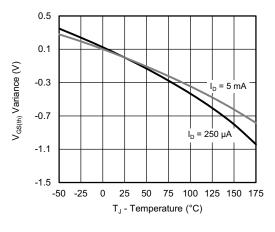
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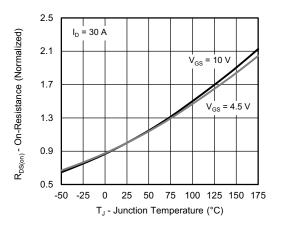
Gate Charge



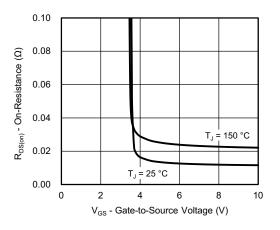
Source Drain Diode Forward Voltage



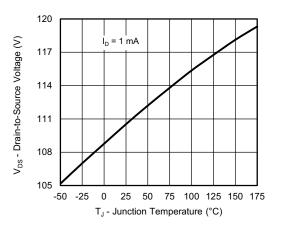
Threshold Voltage



On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

S16-0555-Rev. A, 28-Mar-16

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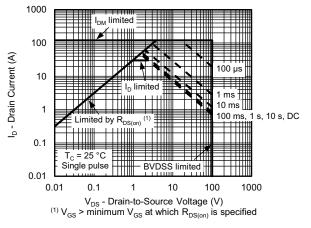
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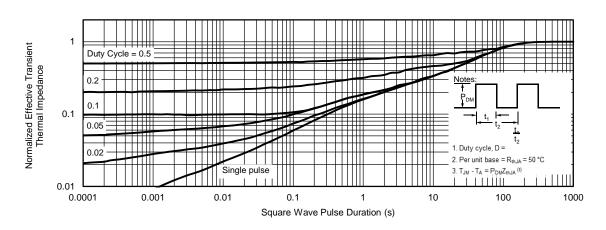
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

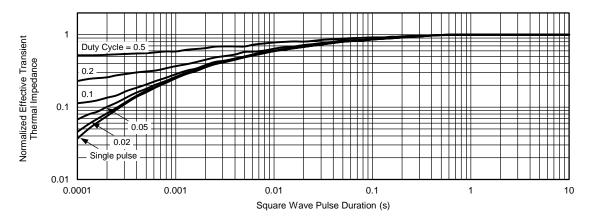


Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

S16-0555-Rev. A, 28-Mar-16

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?78633.





Е b3 Ľ Δ ŝ b2 e1 Б E1

C2 т gage plane height (0.5 mm)

-C

- A1

TO-252AA Case Outline

	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090	0.090 BSC	
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019					

Note

• Dimension L3 is for reference only.





RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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